

# isc N-Channel MOSFET Transistor

# 2SK1925

#### **DESCRIPTION**

- Drain Current –I<sub>D</sub>= 8A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 600V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



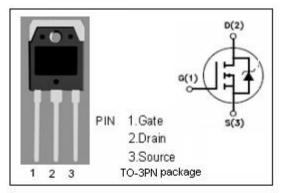
### **APPLICATIONS**

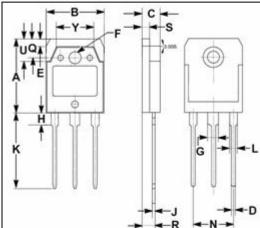
• Ultrahigh-speed switching



### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	600	٧
V <sub>GS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-continuous@ TC=25℃	8	Α
P <sub>tot</sub>	Total Dissipation@TC=25℃	120	W
T <sub>j</sub>	Max. Operating Junction Temperature	rature 150	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}$





	mm		
DIM	MIN	MAX	
Α	19.60	20.10	
В	15.50	15.70	
C	4.70	4.90	
D	0.90	1.10	
E	1.90	2.10	
F	3.40	3.60	
G	2.90	3.20	
Н	3.20	3.40	
J	0.595	0.605	
K	20.00	20.70	
L	1.90	2.20	
N	10.89	10.91	
Q	4.90	5.10	
R	3.35	3.45	
S	1.995	2.100	
U	5.90	6.10	
Y	9.90	10.10	



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# • ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1mA	2		3	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 4A			1.2	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	$V_{GS}$ = $\pm 30V; V_{DS}$ = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 480V; V <sub>GS</sub> = 0			1	mA
Ciss	Input capacitance			1500		
Crss	Reverse transfer capacitance	$V_{DS}$ =20V; $V_{GS}$ =0V; $f_T$ =1MHz		50		pF
Coss	Output capacitance			190		
tr	Rise time			35		
ton	Turn-on time	$V_{GS}$ =10V; $I_D$ =4A; $V_{DD}$ =200V;		20		nc
tf	Fall time	R <sub>L</sub> =50 Ω		100		ns
toff	Turn-off time			350		

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